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Inventors: E. NOEL ABARRA, IWAO OKAMOTO, YOSHIFUMI MIZOSHITA

Title: MAGNETIC RECORDING MEDIUM AND MAGNETIC STORAGE APPARATUS

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Assignors: ABARRA, E. NOEL

Exec Dt: 08/24/1999

OKAMOTO, IWAO

Exec Dt: 08/24/1999

MIZOSHITA, YOSHIFUMI

Exec Dt: 08/24/1999

Assignee: FUJITSU LIMITED

NAKAHARA-KU, KAWASAKI-SHI 1-1 KAMIKODANAKA 4-CHOME

KANAGAWA, JAPAN 211-8

Correspondent: GREER, BURNS & CRAIN, LTD.

PATRICK G. BURNS

233 S. WACKER DRIVE, SUITE 8660

CHICAGO, IL 60606

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If you have any comments or questions concerning the data displayed, contact OPR / Assignments at 703-308-9723 Web interface last modified: Oct. 5, 2002

Patent Assignment Abstract of Title

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Application #: <u>09416364</u> **Filing Dt:** 10/08/1999 Patent #: 6280813 **Issue Dt:** 08/28/2001

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Inventors: MATTHEW JOSEPH CAREY, ERIC EDWARD FULLERTON, BRUCE ALVIN GURNEY, HAL JERVIS

ROSEN, MANFRED ERNST SCHABES

Title: MAGNETIC RECORDING MEDIA WITH ANTIFERROMAGNETICALLY COUPLED

.FERROMAGNETIC_FILMS_AS_THE_RECORDING_LAYER-

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Assignors: CAREY, MATTHEW JOSEPH Exec Dt: 10/05/1999

> FULLERTON, ERIC EDWARD Exec Dt: 10/04/1999

> **GURNEY, BRUCE ALVIN** Exec Dt: 10/07/1999 ROSEN, HAL JERVIS Exec Dt: 10/01/1999

> SCHABES, MANFRED ERNST Exec Dt: 10/01/1999

Assignee: INTERNATIONAL BUSINESS MACHINES CORPORATION

NEW ORCHARD ROAD

ARMONK, NEW YORK 10504

Correspondent: IBM CORPORATION

THOMAS R. BERTHOLD 650 HARRY ROAD (C4TA/J2B)

SAN-JOSE, CA-95120-6099-

Assignment: 2

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Exec Dt: 12/31/2002

Assignor: INTERNATIONAL BUSINESS MACHINES **CORPORATION**

Assignee: MARIANA HDD B.V.

JOHAN HUIZINGALAAN 765

AMSTERDAM, NETHERLANDS 1066VH

Correspondent: ROBERT E. SCHEID

MORRISON & FOERSTER LLP

425 MARKET STREET __ _ _

SAN FRANCISCO, CALIFORNIA 94105-2482

Assignment: 3

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Exec Dt: 12/31/2002 Assignor: MARIANA HDD B.V.

Assignee: HITACHI GLOBAL STORAGE TECHNOLOGIES NETHERLANDS B.V.

LOCATELLIKADE 1 **PARNASSUSTOREN**

1076 AZ AMSTERDAM, NETHERLANDS

ff g

C rrespondent: MORRISON & FOERSTER LLP

ROBERT E. SCHEID 425 MARKET STREET

SAN FRANCISCO, CA 94105-2482

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•	US 6280813 – claim 2	09/425,788 – claim 12
	3 rd ferromagnetic layer 2 nd nonferromagnetic spacer 2 nd ferromagnetic layer nonferromagnetic spacer	Magnetic layer Non-magnetic coupling layer 2 nd exch. structure Ferromagnetic layer Non-magnetic coupling layer 1 st exch. structure
-	1 st ferromagnetic layer substrate	*No substrate claimed but it is conventional in the art to provide a substrate to support the medium. See US 6565718, col. 1, line 65 to col. 2, line 15.
	Magnetic moment per unit area of the 1 st ferromag. layer (M1t1 or Mrt1) not = to magnetic moment per unit area of the 2 nd ferromag. layer (M2t2 or Mrt2). 2 possibilities here: Mrt1>Mrt2 or Mrt1	Remanent magnetization thickness product (Mrt) of the second exchange structure is smaller than that of the first exchange structure. i.e. Mrt1>Mrt2
	1 st ferromagnetic layer is antiferromagnetically exchange coupled to the 2 nd ferromagnetic film and the 3 rd ferromagnetic film is antiferromagnetically exchange coupled to the 2 nd ferromagnetic film	Magnetizations of ferromagnetic layers of 1 st and 2 nd exchange structures are antiparallel The ferromagnetic layer underlying the magnetic layer and the magnetic layer have antiparallel magnetizations. (* "antiparallel" in this context is the equivalent of saying that the layers are antiferromagnetically coupled)
	Magnetic recording structure exhibits a hysteresis loop with 2 remanent magnetic states in the absence of an applied magnetic field (Mr) – see ① and ② on attached copy of Figure 3	*There are no claim limitations directed to the features of a hysteresis loop associated with this structure. However, Figure 6 of this application shows a hysteresis loop for the claimed structure that is very close in shape to the hysteresis loop set forth in Fig. 3 of US 6280813. Therefore, the structure set forth in the present claim inherently satisfies the limitations directed to the hysteresis loop set forth in claim 2 of US 6280813.
	-Orientations of magnetic moments of 1 st and 2 nd ferromagnetic layers are antiparallel in each remanent state -1 st ferromagnetic film's moment orientation (→) in one remanent state is antiparallel to its orientation in the other remanent state (←) - see ③ and ④ on attached copy of Figure 3	Based on this figure, it is clear that there are 2 remanent magnetic-states in the absence of an applied field. The orientations of the magnetic moments of the ferromagnetic layers are not diagramed but appear to be inherent features of the claimed structure based on the shape of the hysteresis loop.

US 6280813 – claim 2	09/425,788 – claim 12
and communication to	No.
3 rd ferromagnetic layer	Magnetic layer
2 nd nonferromagnetic spacer	Non-magnetic coupling layer 2 nd exch. structure
2 nd ferromagnetic layer	Ferromagnetic layer
nonferromagnetic spacer	Non-magnetic coupling layer 1 st exch. structure
_1st ferromagnetic-layer	-Ferromagnetic-layer
substrate	*No substrate claimed but it is conventional in
· ·	the art to provide a substrate to support the
	medium. See US 656718, col. 1, line 65 to col. 2,
	line 15. 6565718
Magnetic moment per unit area of the 1 st	Remanent magnetization thickness product (Mrt)
ferromag. layer (M1t1 or Mrt1) not = to	of the second exchange structure is smaller than
magnetic moment per unit area of the 2 nd	that of the first exchange structure.
ferromag. layer (M2t2 or Mrt2).	
2 possibilities here: Mrt1>Mrt2 or	i.e. Mrt1>Mrt2
Mrt1 <mrt2< td=""><td></td></mrt2<>	
1 st ferromagnetic layer is	Magnetizations of ferromagnetic layers of 1 st and
antiferromagnetically exchange coupled to	2 nd exchange structures are antiparallel
the 2 nd ferromagnetic film and the 3 rd	The ferromagnetic layer underlying the magnetic
ferromagnetic film is antiferromagnetically	layer and the magnetic layer have antiparallel
exchange coupled to the 2 nd ferromagnetic	magnetizations.
film	(* "antiparallel" in this context is the equivalent
	of saying that the layers are antiferromagnetically
	coupled)
Magnetic recording structure exhibits a	*There are no claim limitations directed to the
hysteresis loop with 2 remanent magnetic	features of a hysteresis loop associated with this
states in the absence of an applied magnetic	structure. However, Figure 6 of this application
field (Mr) – see ① and ② on attached copy	shows a hysteresis loop that is very close in shape
of Figure 4	to the hysteresis loop set forth in Fig. 4 of US
	6280813. Therefore inherent
-Orientations of magnetic moments of 1st	Based on this figure, it is clear that there are 2
and 2 nd ferromagnetic layers are	remanent magnetic states in the absence of an
antiparallel in each remanent state	applied field. The orientations of the magnetic
-1 st ferromagnetic film's moment	moments of the ferromagnetic layers are not
orientation (\rightarrow) in one remanent state is	diagramed_but_appear_to be inherent features-of
antiparallel to its orientation in the other	the claimed structure based on the shape of the
remanent state (←)— see ③ and ④ on	hysteresis loop.
attached copy of Figure 4	

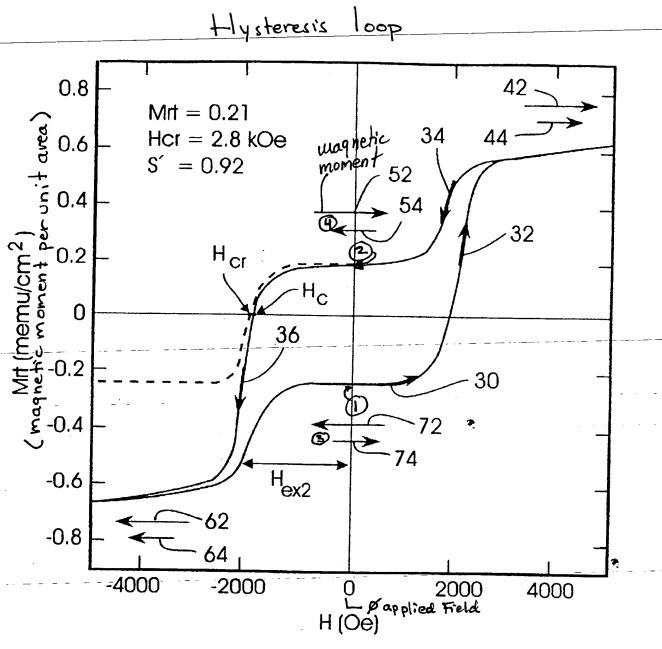


FIG. 4

() (2): remanent state (Mr) = measure for magnetism in the absence of an applied magnetic field (H)

